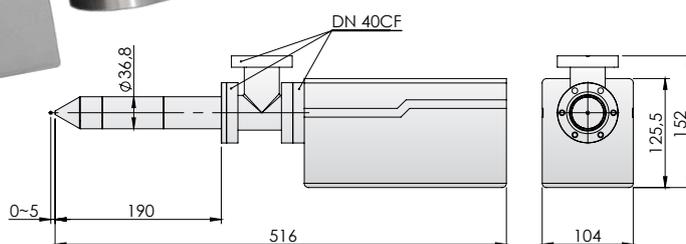
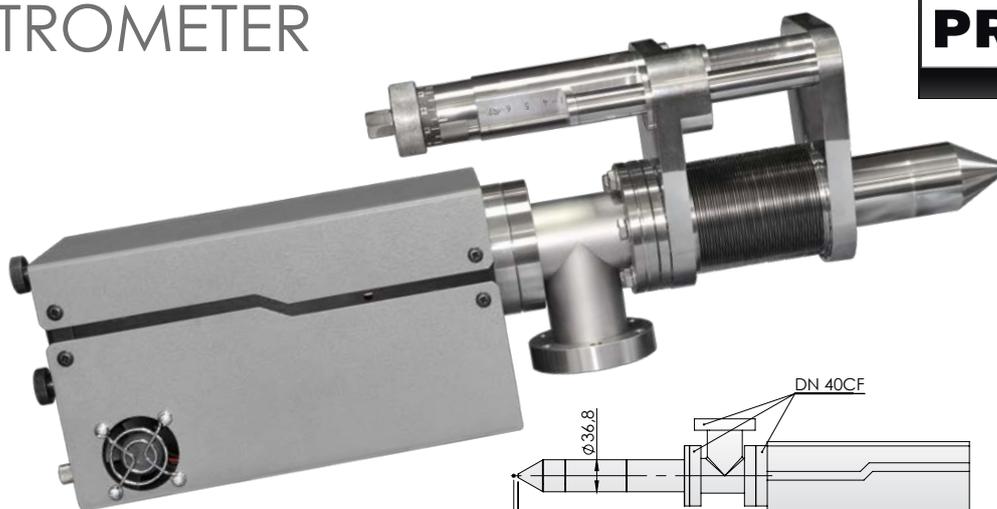


# TDS 40A1

## THERMAL DESORPTION SPECTROMETER



TDS

### DESCRIPTION

The TDS 40A1 is designed for Temperature Programmed Desorption (TPD) applications, also known as Thermal Desorption Spectroscopy (TDS). TPD involves heating a sample under UHV conditions and simultaneously measuring a number of desorbing gas species as a function of sample temperature. A custom designed conical sampling end piece ensures the best possible response to desorbing species.

### FEATURES

- Completely programmable
- Unique filament design
- Wide operation temperature range

### OPTIONS

- Quadrupole MS: 100, 200 or 300 amu
- High stability linear shift
- Differential pumping (1 stage)



PTS 1000

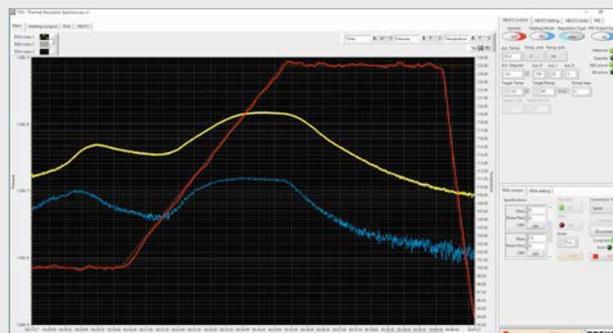
PTS 1200

Dedicated sample holders (optional)

### TECHNICAL DATA

Mounting flange	DN 40CF (non-rotatable)
Bakeout temperature	up to 150 °C
Insertion length	190 mm (other on request) OD: 36.8 mm
Mass range	1 to 300 amu
Mass filter	quadrupole
Detector type	electron multiplier (EM)
Resolution	better than 0.5 amu
Sensitivity	$2 \times 10^{-4}$ A/Torr (FC), $< 200$ A/Torr (EM)
Minimum detectable partial pressure	$5 \times 10^{-11}$ Torr (FC), $5 \times 10^{-14}$ Torr (EM)
Working pressure	$< 10^{-4}$ Torr to UHV (FC) $< 10^{-6}$ Torr to UHV (EM)

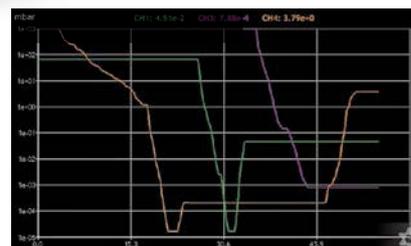
### TDS/TPD SOFTWARE APPLICATION



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# HEAT3-PS

## SAMPLE HEATING POWER SUPPLY



Real time pressure charts (data export possibility).

### DESCRIPTION

The HEAT3-PS is used for resistive heating or electron bombardment heating. The power supply can also be used for effusion cell evaporators. The unit is equipped with a PID temperature controller. Ramp heating function control sample temperature to protect sample from damage. Sample overheating can also be protected by setting the voltage and current limits. The unit can be operated in auto mode (with temperature control) or manual mode (without temperature control). The unit is equipped with autosave function (the device save your parameters, preset and apply them automatically after restart).

### FEATURES

- **Dual heating mode: resistive and electron bombardment**
- Wide range temperature measurement (1.4 - 2473.15 K)
- **2D real time chart module**
- High efficiency
- Setpoint based over-voltage and over-current output protection
- Fully manual or PID temperature controlled (by setpoint and ramp)
- Process temperature control with built-in PID controller (with autotuning function for optimized process PID parameters)
- Various kind of temperature sensors: thermocouples K/C/E/N (other on request), Pt, diode
- Multiple I/O (10 digital/4 analog) - individual reprogrammable
- High resolution (16-bit analog I/O, 0.1 K temp.)
- One vacuum channel for active gauges
- **Shutter control function** - up to 2\* shutters (e.g. shutters of sources or manipulators)
- Mobile solutions for remote access and control
- Customised menu options (for robust and effectivity)
- Support (easy firmware update via USB)

\* for double DC module version, 1 shutter per channel

### OPTIONS

- **Second DC module** available: **two resistive heating zones** with independent control, or one resistive heating zone with **higher output power** (90V, 17A or 45V, 30A) excluding EB module
- Analog I/O card for vacuum measurement (1 gauge)

### TECHNICAL DATA

Supply voltage	100-130VAC/200-260 VAC, 50-60Hz (power consumption max 1600 W)
<b>Resistive heating</b> mode parameters	45 V, 17 A - standard; other versions on request
<b>EB heating</b> mode parameters	1000 V, 300 mA - standard; other versions on request
Temperature range	• <b>273.15 K - 2473.15 K</b> for type C thermocouple (dependent on sample holder type or evaporator)  • <b>73.15 K - 1645.15 K</b> for type K thermocouple • <b>1.4 K - 500 K</b> for DT670/DT470 silicon diodes (dependent on sample holder type and conditions in chamber)
Temperature independent inputs	2 - for thermocouples K/C/E/N 2 - for silicon diodes DT670/DT470
Temperature setpoint ramp rate	adjustable from 0.1 K to 1000 K/ s min h
$\Delta T$ setpoint	0.1 to 5.0 K/s
Vacuum measurement (optional)	CTR90, TTR91, TTR211, PTR225, PTR90, ITR90, ITR100, Baratron, ANALOG IN, PG105, MG13/14, PKR251/360/361, PCR280, ATMION
Communication interface	RS232/485, Ethernet
Communication protocol	MODBUS-TCP
User interface	7" TFT display with touchscreen, digital encoder
Interface languages	English, German, Polish
Dimensions	448.8 × 132.5 × 375 mm (W×H×D), 19" rack mountable
Weight (approx.)	8.8 kg (for standard version)

### APPLICATION

- Any thermal process according to the specifications
- Effusion cells supply
- Sample holders heating
- Thermal monitoring



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HEAT3-PS